

SiC Schottky Barrier Diode

V_R	650V
I _F	4A
Q_{C}	11nC

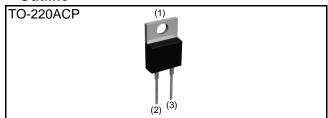
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

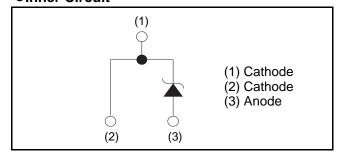
Construction

Silicon carbide epitaxial planar type

●Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS304AH

● Absolute Maximum Ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	I current (T _c =140°C)	l _F	4	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		27	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	22	A
current	PW=10μs square, T _j =25°C		100	А
Repetitive peak forward current		I _{FRM}	20 *1	А
1≦PW≦10ms, T _j =25°C		.∫ i²dt	3.6	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		J I-at	2.4	A ² s
Total power disspation		P_D	34 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter	Cumbal	l Conditions -	Values			Linit
Parameter	Symbol		Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =20μA	650	-	-	V
	V _F	I _F =4A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =4A,T _j =150°C	-	1.44	1.71	V
		I _F =4A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.012	20.0	μА
		V _R =650V,T _j =150°C	-	0.8	80	μΑ
		V _R =650V,T _j =175°C	-	2.4	-	μА
Total capacitance	С	V _R =1V,f=1MHz	-	200	-	pF
		V _R =650V,f=1MHz	-	18	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	11	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	14	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	48	1	mJ

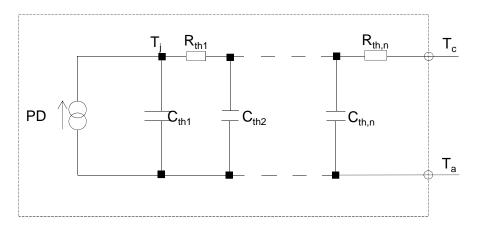
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
Thermal resistance	R _{th(j-c)}	-	-	3.0	4.4	°C/W

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	3.91E-02	
R _{th2}	3.76E-01	K/W
R _{th3}	2.54E+00	

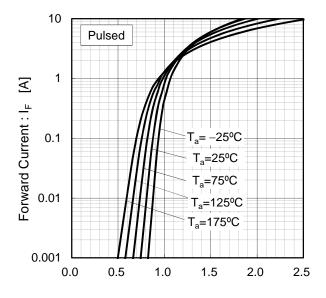
Symbol	Value	Unit
C _{th1}	1.01E-04	
C _{th2}	4.02E-04	Ws/K
C _{th3}	1.19E-03	



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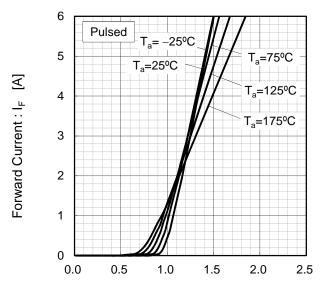
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



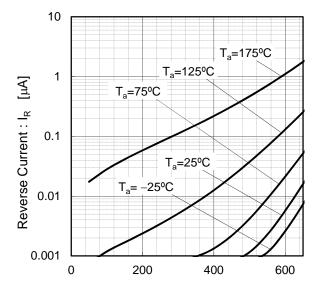
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



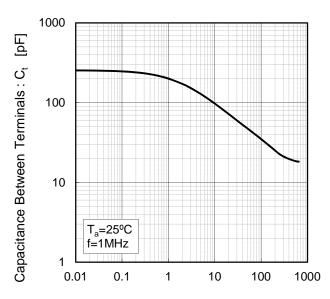
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

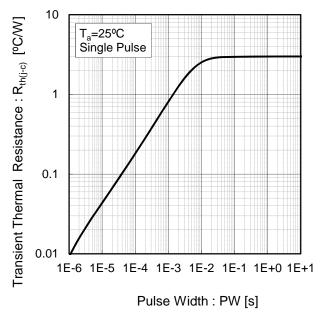
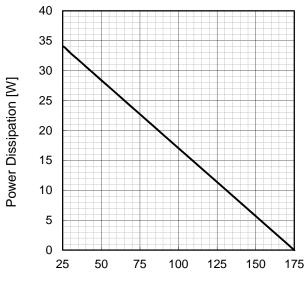
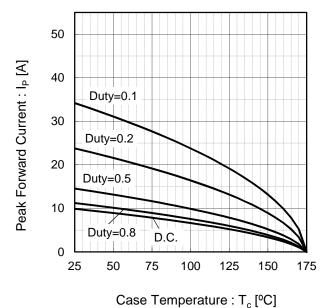


Fig.6 Power Dissipation



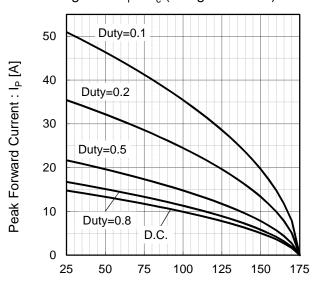
Case Temperature : T_c [°C]

Fig.7*3 Maximum peak forward current derating curve I_P - T_c



*3 Based on max Vf, max $R_{\text{th(j-c)}}$ Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve $I_P - T_c$ (Not guaranteed)

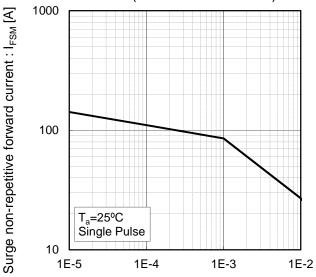


Case Temperature : T_c [°C]

 $^{\star}4$ Based on typ Vf, typ $R_{th(j\text{-}c)}$ Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

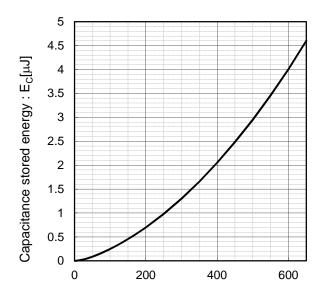
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



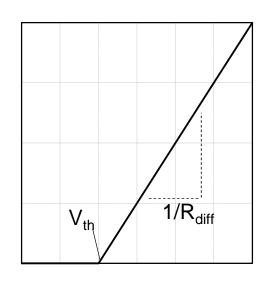
Pulse Width: PW [s]

Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Fig.11 Equivalent forward current curve



Forward Voltage : V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\:T_{j}\:\right) = a_{0} + a_{1}\:T_{j} \\ &R_{diff}\left(\:T_{j}\:\right) = b_{0} + b_{1}\:T_{j} + b_{2}\:T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.66E-01	V
a ₁	- 1.10E-03	V/°C
b_0	8.80E-02	Ω
b ₁	1.87E-04	Ω/°C
b ₂	1.92E-06	Ω/°C ²

 T_i in °C; -55 °C < T_i < 175°C; I_F < 8A

Forward Current: IF

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